

PSMN6R3-120ES

N-channel 120 V 6.7 mΩ standard level MOSFET in I2PAK
8 May 2013 Product data sheet

1. General description

Standard level N-channel MOSFET in I2PAK package qualified to 175 °C. This product is designed and qualified for use in a wide range of industrial, communications and domestic power supply equipment.

2. Features and benefits

- High efficiency due to low switching and conduction losses
- Improved dynamic avalanche performance
- Suitable for standard level gate drive
- I2PAK package for slimline adaptors & height constrained applications

3. Applications

- AC-to-DC power supply
- Synchronous rectification
- Motor control
- Slimline adaptors & chargers

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	-	120	V
I _D	drain current	T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>	-	-	70	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>	-	-	405	W
Static charac	teristics		'			
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 12	4	5.7	6.7	mΩ
Dynamic cha	racteristics		'			
Q_{GD}	gate-drain charge	V _{GS} = 10 V; I _D = 25 A; V _{DS} = 60 V;	-	61.9	-	nC
Q _{G(tot)}	total gate charge	Fig. 14; Fig. 15	-	207.1	-	nC
Avalanche ru	iggedness		'			
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 70 A; $V_{sup} \le$ 120 V; unclamped; R_{GS} = 50 Ω; Fig. 3	-	-	532	mJ



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D
2	D	drain		
3	S	source		G (S)
mb	D	drain	1 2 3	mbb076 S
			12PAK (SOT226)	

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PSMN6R3-120ES	I2PAK	plastic single-ended package (I2PAK); TO-262	SOT226			

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	120	V
V_{DGR}	drain-gate voltage	$T_j \ge 25$ °C; $T_j \le 175$ °C; $R_{GS} = 20$ kΩ	-	120	V
V_{GS}	gate-source voltage		-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 1</u>	-	70	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 1</u>	-	70	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 \text{ °C}$; Fig. 4	-	280	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>	-	405	W
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
T _{sld(M)}	peak soldering temperature		-	260	°C
Source-drai	n diode				
I _S	source current	T _{mb} = 25 °C	-	70	Α
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$	-	280	Α

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Symbol	Parameter	Conditions	Min	Max	Unit
Avalanche rug	gedness				
E _{DS(AL)} S	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 70 A; $V_{sup} \le$ 120 V; unclamped; R_{GS} = 50 Ω ; Fig. 3	-	532	mJ

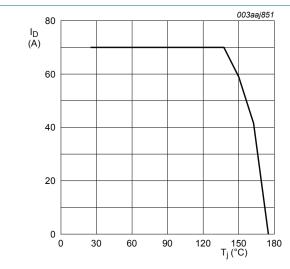


Fig. 1. Continuous drain current as a function of mounting base temperature

$$V_{GS} \ge 10V$$

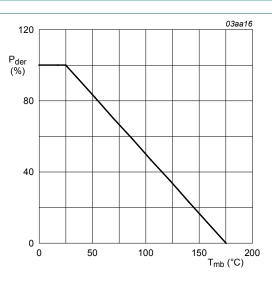


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \,\%$$

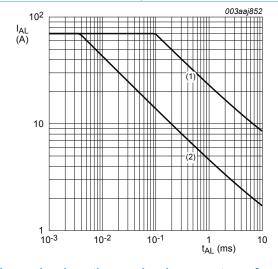


Fig. 3. Single-pulse and repetitive avalanche rating; avalanche current as a function of avalanche time

(1) Single-pulse; $T_j = 25 \,^{\circ}C$.

(2) Single-pulse; $T_j = 125 \,^{\circ}C$.

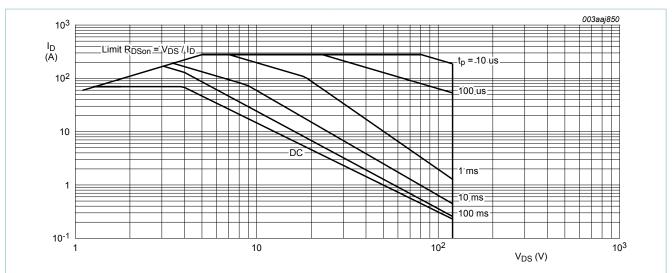


Fig. 4. Safe operating area; continuous and peak drain current as a function of drain-source voltage

 $T_{mb} = 25 \,^{\circ}C; I_{DM}$ is single pulse

8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	0.3	0.37	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	vertical in free air	-	65	-	K/W

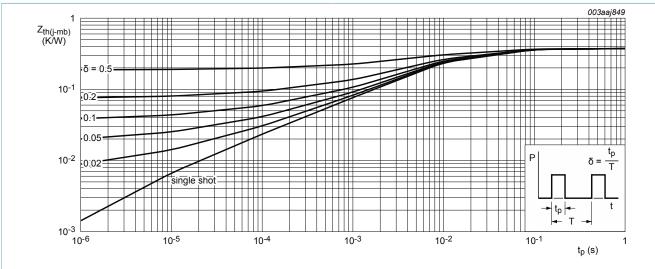


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

9. Characteristics

Table 6 Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics			<u> </u>		
V _{(BR)DSS}	drain-source	I_D = 250 μ A; V_{GS} = 0 V; T_j = 25 °C	120	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	108	-	-	V
V _{GS(th)} gate-source thresho voltage	gate-source threshold voltage	I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 25 °C; Fig. 10; Fig. 11	2	3	4	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 175 °C; Fig. 10; Fig. 11	1	-	-	V
		I_D = 1 mA; V_{DS} = V_{GS} ; T_j = -55 °C; Fig. 10; Fig. 11	-	-	4.6	V
I _{DSS}	drain leakage current	V _{DS} = 120 V; V _{GS} = 0 V; T _j = 25 °C	-	0.1	1	μA
		V _{DS} = 120 V; V _{GS} = 0 V; T _j = 175 °C	-	-	500	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA
R _{DSon} drain-source on-state resistance		V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 12	4	5.7	6.7	mΩ
	V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 13; Fig. 12	-	16.5	19.4	mΩ	
R_G	internal gate resistance (AC)	f = 1 MHz	0.44	0.88	1.76	Ω
Dynamic ch	naracteristics		'	-	'	,
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 60 V; V _{GS} = 10 V;	-	207.1	-	nC
Q _{GS}	gate-source charge	Fig. 14; Fig. 15	-	43.2	-	nC
Q _{GS(th)}	pre-threshold gate- source charge		-	29.8	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	13.4	-	nC
Q_{GD}	gate-drain charge		-	61.9	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	I _D = 25 A; V _{DS} = 60 V; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	4.3	-	V
C _{iss}	input capacitance	V _{DS} = 60 V; V _{GS} = 0 V; f = 1 MHz;	-	11384	-	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 16</u>	-	534	-	pF
C _{rss}	reverse transfer capacitance		-	358	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 60 V; R_L = 2.4 Ω ; V_{GS} = 10 V;	-	42.1	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$; $T_j = 25 ^{\circ}C$	-	58.2	-	ns

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$t_{d(off)}$	turn-off delay time		-	142.1	-	ns
t _f	fall time		-	67.7	-	ns
Source-dra	in diode		'			
V_{SD}	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}; Fig. 17$	-	0.79	1.2	V
t _{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$	-	76.1	-	ns
Q _r	recovered charge	V _{DS} = 60 V	-	264.2	-	nC

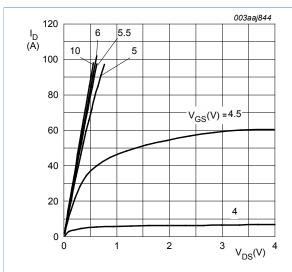


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

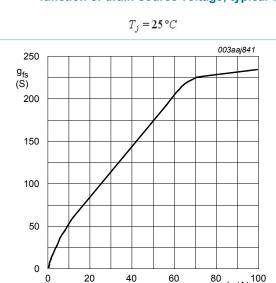


Fig. 8. Forward transconductance as a function of drain current; typical values

$$T_j = 25 \,^{\circ}C; V_{DS} = 10 \, V$$

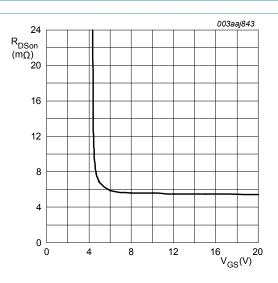


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_i = 25 \,^{\circ}C$$

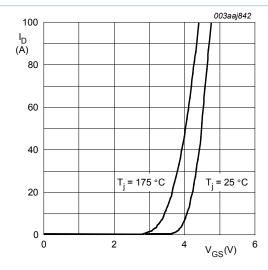


Fig. 9. Transfer characteristics: drain current as a function of gate-source voltage; typical values

$$V_{DS} > I_D \times R_{DSon}$$

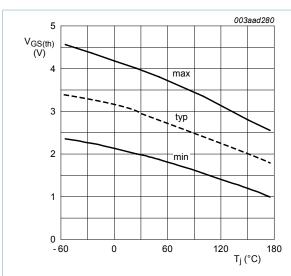


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$$I_D = 1 \text{ mA}; \ V_{DS} = V_{GS}$$

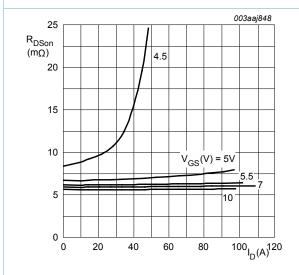


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$$T_j = 25 \,^{\circ}C$$

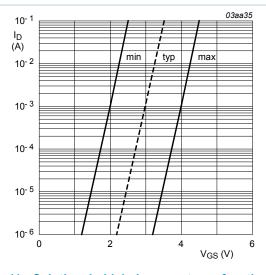


Fig. 11. Sub-threshold drain current as a function of gate-source voltage

$$T_j = 25 \,^{\circ}C; V_{DS} = 5V$$

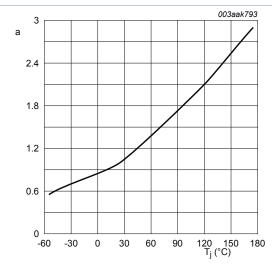


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon (25^{\circ}C)}}$$

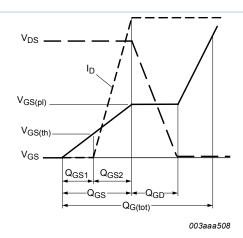


Fig. 14. Gate charge waveform definitions

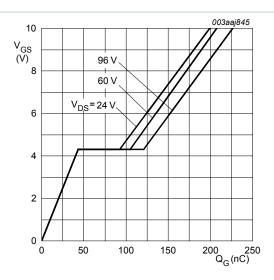


Fig. 15. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25 \,^{\circ}C; I_D = 25 A$$

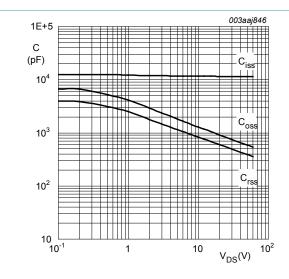


Fig. 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{\mathit{GS}}\!=\!\mathbf{0}\,V; f=\!\mathbf{1}MHz$$

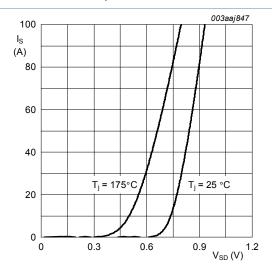


Fig. 17. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

$$V_{GS} = 0 V$$

10. Package outline

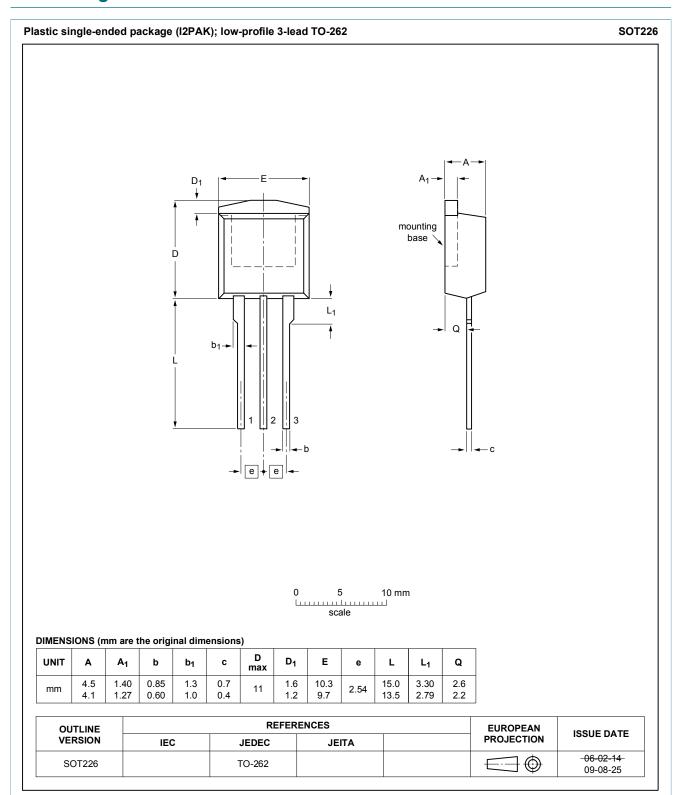


Fig. 18. Package outline I2PAK (SOT226)

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